NSN 5961-01-157-2801

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-157-2801 **Inclosure Material:** Glass **Overall Length:** 0.200 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.090 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes forward current, average nanoamperes **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Non magnetic; junction pattern arrangement: pn **Test Data Document:** 96214-507151 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**